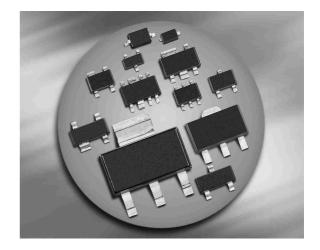


#### **Silicon Schottky Diode**

- General-purpose diode for high-speed switching
- Circuit protection
- Voltage clamping
- High-level detecting and mixing
- Pb-free (RoHS compliant) package
- Qualified according AEC Q101<sup>1</sup>)





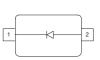


**BAS140W BAS40-02L** 

BAS40-04

BAS40-05 BAS40-05W

BAS40-06 BAS40-06W





**BAS40** 







BAS40-07 BAS40-07W



**ESD** (Electrostatic discharge) sensitive device, observe handling precaution!

Туре	Package	Configuration	Marking
BAS140W	SOD323	single	white 4
BAS40	SOT23	single	43s
BAS40-02L*	TSLP-2-1	single, leadless	FF
BAS40-04	SOT23	series	44s
BAS40-05	SOT23	common cathode	45s
BAS40-05W	SOT323	common cathode	45s
BAS40-06	SOT23	common anode	46s
BAS40-06W	SOT323	common anode	46s
BAS40-07	SOT143	parallel pair	47s
BAS40-07W	SOT343	parallel pair	47s

<sup>1\*</sup> BAS40-02L is not qualified according AEC Q101



**Maximum Ratings** at  $T_A$  = 25 °C, unless otherwise specified

Parameter	Symbol	Value	Unit
Diode reverse voltage	$V_{R}$	40	V
Forward current	I <sub>F</sub>	120	mA
Non-repetitive peak surge forward current	I <sub>FSM</sub>	200	
<i>t</i> ≤ 10ms			
Total power dissipation	P <sub>tot</sub>		mW
BAS140W, <i>T</i> <sub>S</sub> ≤ 113°C		250	
BAS40, BAS40-07, <i>T</i> <sub>S</sub> ≤ 81°C		250	
BAS40-02L, $T_S \leq 127^{\circ}C$		250	
BAS40-04, BAS40-06, $T_{S} \le 56^{\circ}\text{C}$		250	
BAS40-06W, $T_S \leq 106^{\circ}C$		250	
BAS40-05, <i>T</i> <sub>S</sub> ≤ 31°C		250	
BAS40-05W, $T_S \leq 98^{\circ}C$		250	
BAS40-07W, $T_{S} \le 118^{\circ}C$		250	
Junction temperature	T <sub>j</sub>	150	°C
Operating temperature range	$T_{op}$	-55150	
Storage temperature	T <sub>stg</sub>	-55150	

#### **Thermal Resistance**

Parameter	Symbol	Value	Unit
Junction - soldering point <sup>1)</sup>	R <sub>thJS</sub>		K/W
BAS140W		≤ 150	
BAS40, BAS40-07		≤ 275	
BAS40-02L		≤ 90	
BAS40-04, BAS40-06		≤ 375	
BAS40-06W		≤ 175	
BAS40-05		≤ 475	
BAS40-05W		≤ 205	
BAS40-07W		≤ 125	

 $<sup>^{1}</sup>$ For calculation of  $R_{thJA}$  please refer to Application Note AN077 (Thermal Resistance Calculation)



**Electrical Characteristics** at  $T_A = 25$ °C, unless otherwise specified

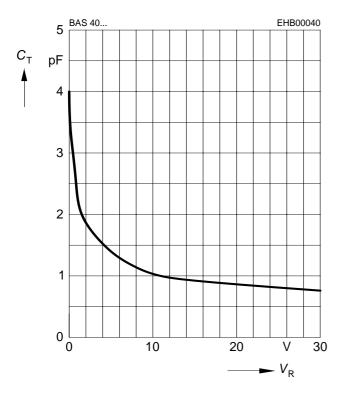
Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics	1		1	1	
Breakdown voltage	$V_{(BR)}$	40		-	V
$I_{(BR)} = 10 \ \mu A$					
Reverse current	$I_{R}$	-	-	1	μΑ
<i>V</i> <sub>R</sub> = 30 V					
Forward voltage	$V_{F}$				mV
I <sub>F</sub> = 1 mA		250	310	380	
<i>I</i> <sub>F</sub> = 10 mA		350	450	500	
<i>I</i> <sub>F</sub> = 40 mA		600	720	1000	
Forward voltage matching <sup>1)</sup>	ΔV <sub>F</sub>	-	-	20	
<i>I</i> <sub>F</sub> = 10 mA					
AC Characteristics		<u> </u>			
Diode capacitance	$c_{T}$	-	3	5	pF
$V_{R} = 0$ , $f = 1 \; MHz$					
Differential forward resistance	R <sub>F</sub>	-	10	-	Ω
$I_{\rm F}$ = 10 mA, $f$ = 10 kHz					
Charge carrier life time	τ <sub>rr</sub>	-	-	100	ps
<i>I</i> <sub>F</sub> = 25 mA					

 $<sup>^{1}\!\</sup>Delta V_{\mathrm{F}}$  is the difference between lowest and highest  $V_{\mathrm{F}}$  in a multiple diode component.



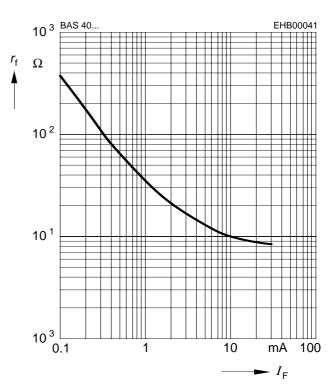
# Diode capacitance $C_T = f(V_R)$

f = 1MHz



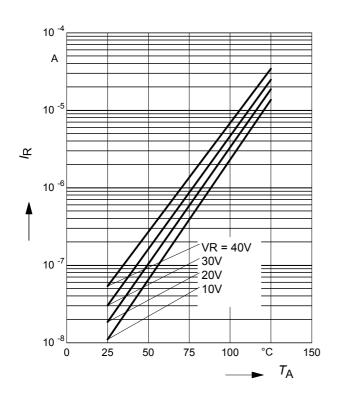
### Forward resistance $r_f = f(I_F)$

f = 10 kHz



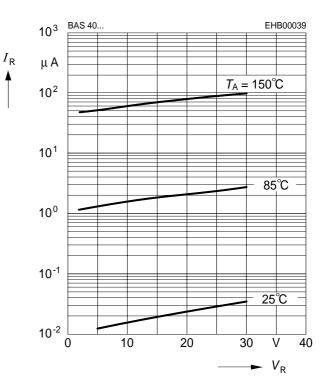
## Reverse current $I_R = f(T_A)$

 $V_{R}$  = Parameter



## Reverse current $I_R = f(V_R)$

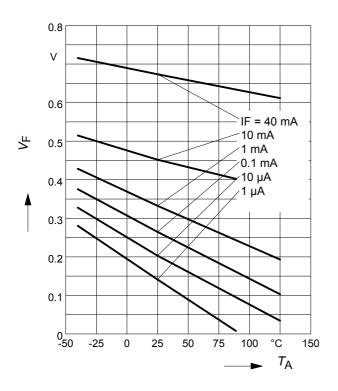
 $T_A$  = Parameter





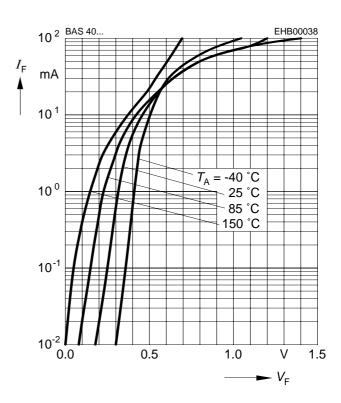
# Forward Voltage $V_F = f(T_A)$

 $I_{\mathsf{F}}$  = Parameter



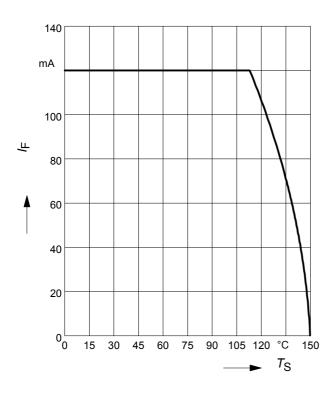
### Forward current $I_F = f(V_F)$

 $T_A$  = Parameter



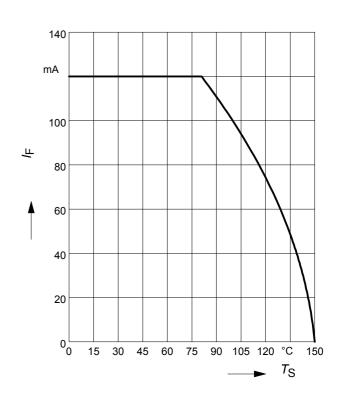
## Forward current $I_F = f(T_S)$

BAS140W



# Forward current $I_F = f(T_S)$

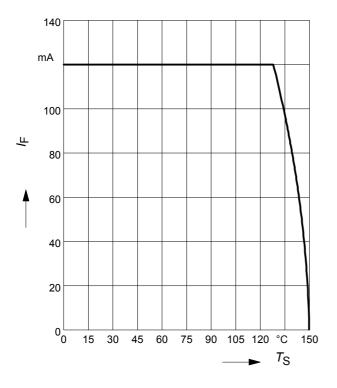
BAS40, BAS40-07





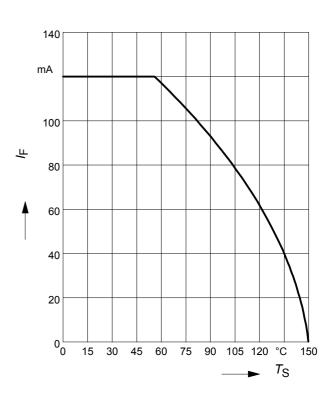
# Forward current $I_F = f(T_S)$

BAS40-02L



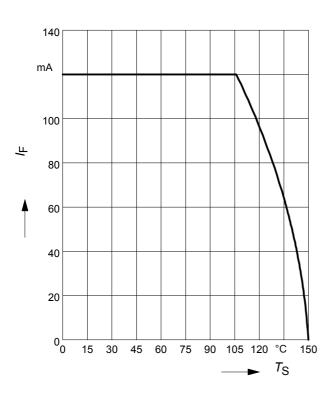
# Forward current $I_F = f(T_S)$

BAS40-04, BAS40-06



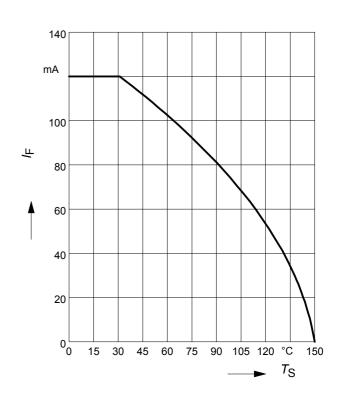
# Forward current $I_F = f(T_S)$

BAS40-06W



## Forward current $I_F = f(T_S)$

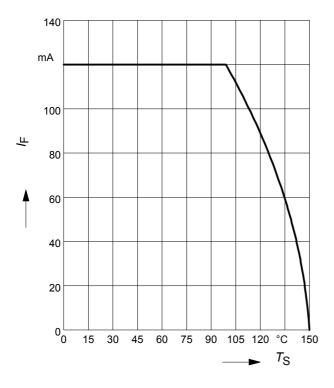
BAS40-05





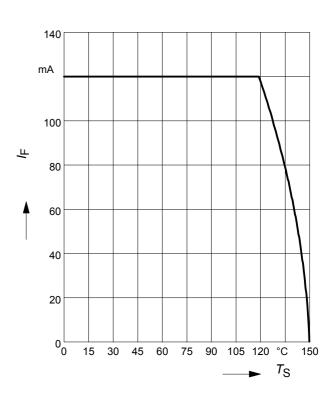
## Forward current $I_F = f(T_S)$

BAS40-05W

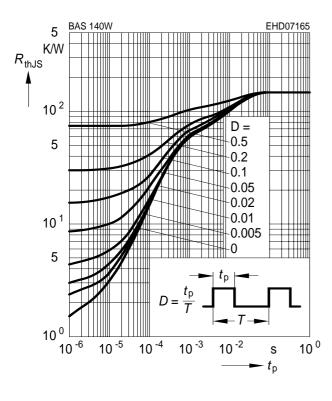


### Forward current $I_F = f(T_S)$

BAS40-07W

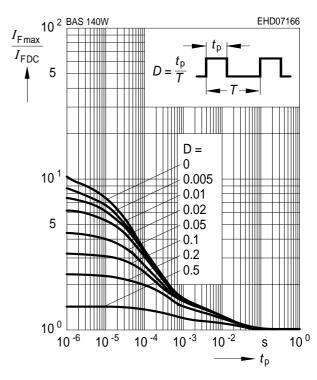


# **Permissible Puls Load** $R_{thJS} = f(t_p)$ BAS140W



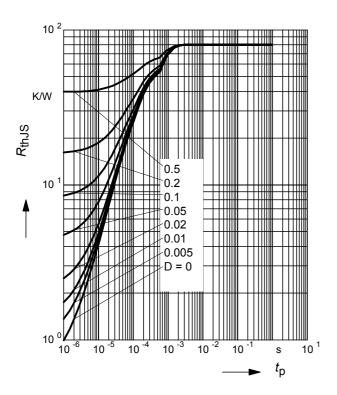
#### **Permissible Pulse Load**

 $I_{\text{Fmax}}/I_{\text{FDC}} = f(t_{\text{p}})$ BAS140W

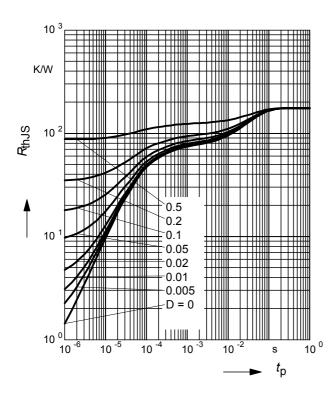




# **Permissible Puls Load** $R_{thJS} = f(t_p)$ BAS40-02L

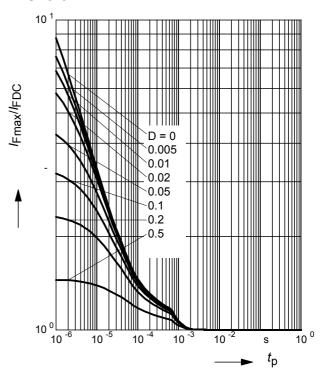


# **Permissible Puls Load** $R_{thJS} = f(t_p)$ BAS40-06W



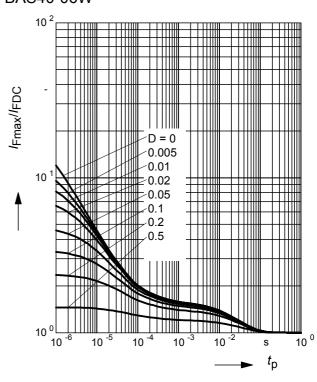
#### **Permissible Pulse Load**

 $I_{\text{Fmax}}/I_{\text{FDC}} = f(t_{\text{p}})$ BAS40-02L



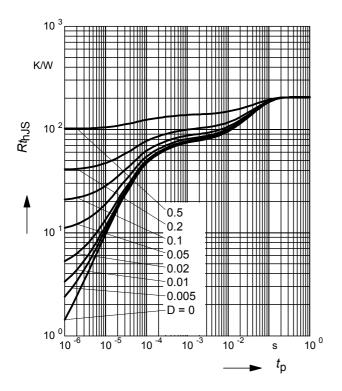
#### **Permissible Pulse Load**

 $I_{\text{Fmax}}/I_{\text{FDC}} = f(t_{\text{p}})$ BAS40-06W



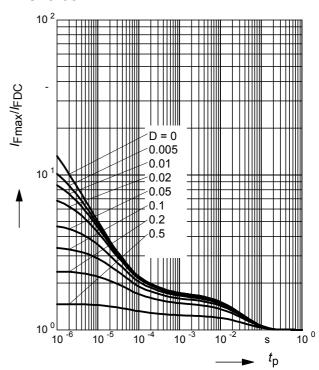


# **Permissible Puls Load** $R_{thJS} = f(t_p)$ BAS40-05W

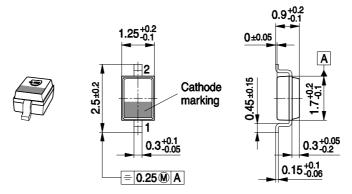


#### **Permissible Pulse Load**

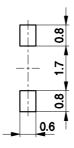
$$I_{\text{Fmax}}/I_{\text{FDC}} = f(t_{\text{p}})$$
  
BAS40-05W



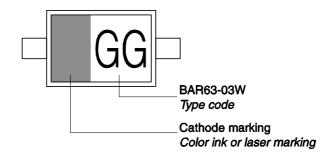




#### **Foot Print**

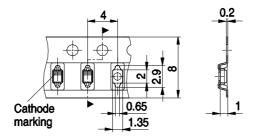


### Marking Layout (Example)

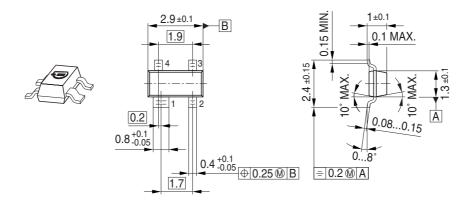


## Standard Packing

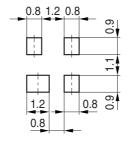
Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel



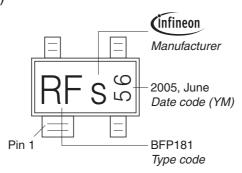




#### Foot Print

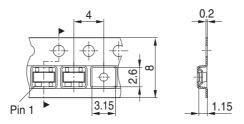


### Marking Layout (Example)

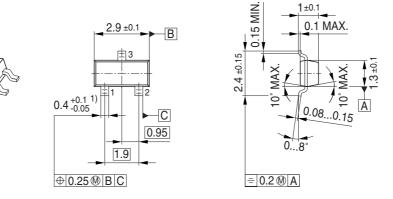


## Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel

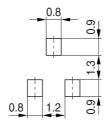




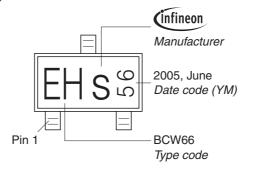


1) Lead width can be 0.6 max. in dambar area

#### Foot Print

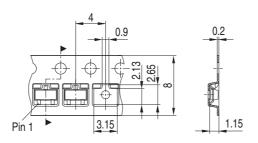


### Marking Layout (Example)



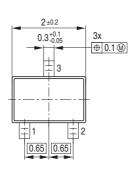
## Standard Packing

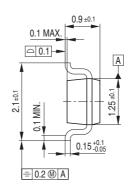
Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel



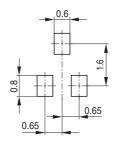




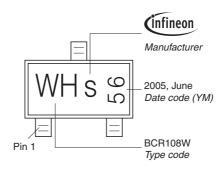




#### Foot Print

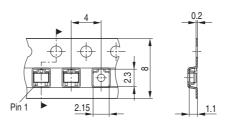


### Marking Layout (Example)

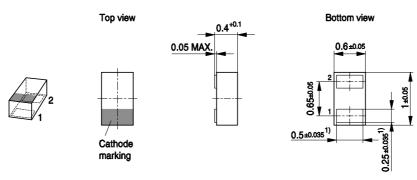


## Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel



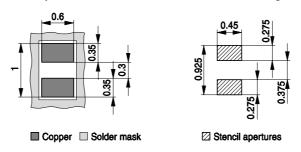




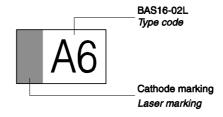
1) Dimension applies to plated terminal

#### **Foot Print**

For board assembly information please refer to Infineon website "Packages"

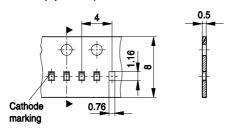


### Marking Layout (Example)



#### Standard Packing

Reel ø180 mm = 15.000 Pieces/Reel Reel ø330 mm = 50.000 Pieces/Reel (optional)





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